

1 550 nm InGaAsP MQW-DFB LASER DIODE MODULE CW LIGHT SOURCE FOR DWDM APPLICATIONS

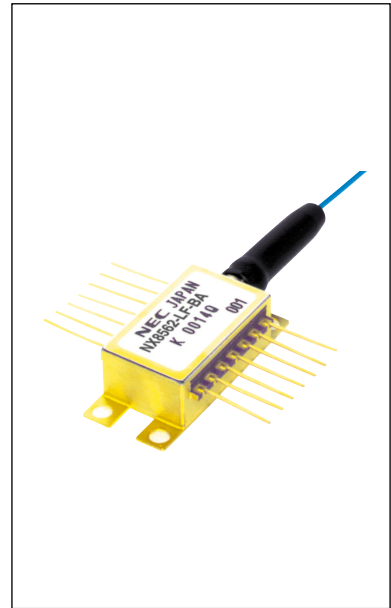
DESCRIPTION

The NX8562LF is a 1 550 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode module with Polarization Maintain Fiber (PMF).

It is designed as Continuous Wave (CW) light source and ideal for optical transmission systems with external modulators. The device is available for Dense Wavelength Division Multiplexing (DWDM) wavelengths based on ITU-T recommendations, enabling a wide range of applications.

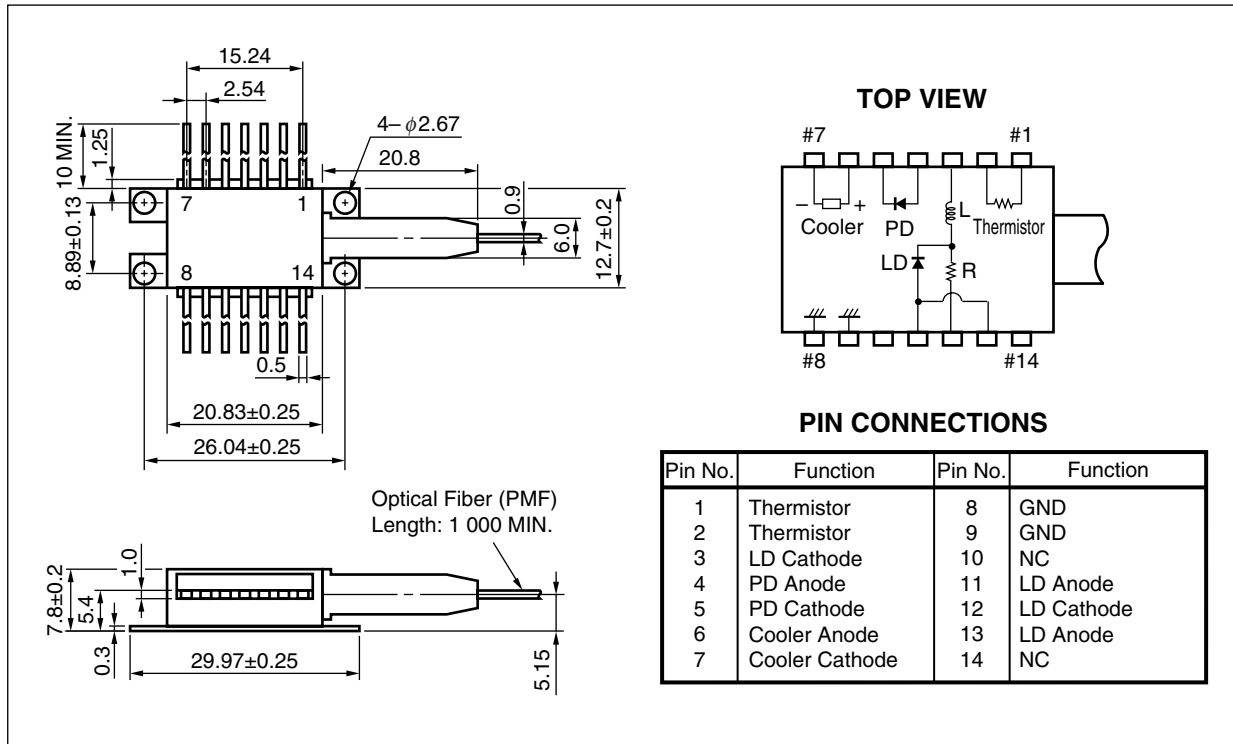
FEATURES

- Output power $P_r = 20 \text{ mW MIN.}$
- Available for DWDM wavelengths based on ITU-T recommendations (100 GHz grid, please refer to the **ORDERING INFORMATION**)
- Internal thermo-electric cooler and isolator
- Hermetically sealed 14-pin butterfly package
- Polarization maintain fiber pigtail



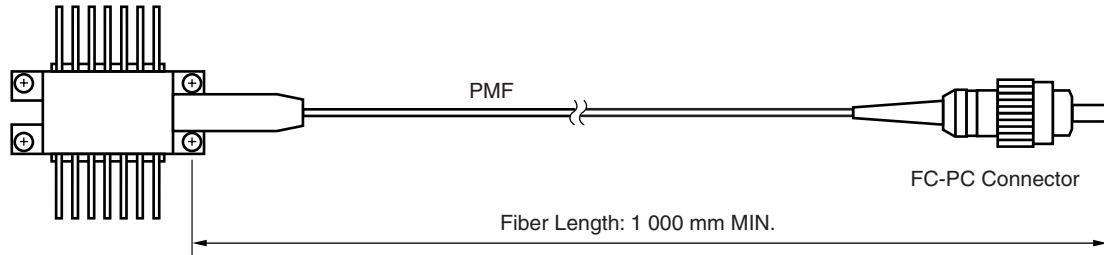
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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

★ PACKAGE DIMENSIONS (UNIT: mm)



OPTICAL FIBER DIMENSIONS (UNIT: mm)

Parameter	Specification	Unit
Outer Diameter	0.9±0.1	mm
Minimum Fiber Bending Radius	30	mm
Fiber Length	1 000 MIN.	mm



★ ORDERING INFORMATION

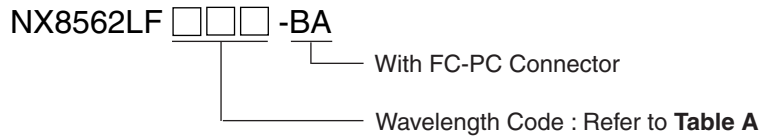


Table A: DWDM wavelength based on ITU-T recommendations (@T_{LD} = T_{set}) (1/2)

Wavelength Code	ITU-T Wavelength ^{*1} (nm)	Frequency (THz)	Wavelength Code	ITU-T Wavelength ^{*1} (nm)	Frequency (THz)
279	1 527.99	196.20	485	1 548.51	193.60
287	1 528.77	196.10	493	1 549.31	193.50
295	1 529.55	196.00	501	1 550.11	193.40
303	1 530.33	195.90	509	1 550.91	193.30
311	1 531.11	195.80	517	1 551.72	193.20
318	1 531.89	195.70	525	1 552.52	193.10
326	1 532.68	195.60	533	1 553.32	193.00
334	1 533.46	195.50	541	1 554.13	192.90
342	1 534.25	195.40	549	1 554.94	192.80
350	1 535.03	195.30	557	1 555.74	192.70
358	1 535.82	195.20	565	1 556.55	192.60
366	1 536.60	195.10	573	1 557.36	192.50
373	1 537.39	195.00	581	1 558.17	192.40
381	1 538.18	194.90	589	1 558.98	192.30
389	1 538.97	194.80	597	1 559.79	192.20
397	1 539.76	194.70	606	1 560.60	192.10
405	1 540.55	194.60	614	1 561.41	192.00
413	1 541.34	194.50	622	1 562.23	191.90
421	1 542.14	194.40	630	1 563.04	191.80
429	1 542.93	194.30	638	1 563.86	191.70
437	1 543.73	194.20	646	1 564.67	191.60
445	1 544.52	194.10	654	1 565.49	191.50
453	1 545.32	194.00	663	1 566.31	191.40
461	1 546.11	193.90	671	1 567.13	191.30
469	1 546.91	193.80	679	1 567.95	191.20
477	1 547.71	193.70	687	1 568.77	191.10

*1 The value which omitted and computed the 3rd place below the decimal point

Table A: DWDM wavelength based on ITU-T recommendations (@T_{LD} = T_{set}) (2/2)

Wavelength Code	ITU-T Wavelength ^{*1} (nm)	Frequency (THz)	Wavelength Code	ITU-T Wavelength ^{*1} (nm)	Frequency (THz)
695	1 569.59	191.00	912	1 591.25	188.40
704	1 570.41	190.90	921	1 592.10	188.30
712	1 571.23	190.80	929	1 592.94	188.20
720	1 572.06	190.70	937	1 593.79	188.10
728	1 572.88	190.60	946	1 594.64	188.00
737	1 573.71	190.50	954	1 595.48	187.90
745	1 574.54	190.40	963	1 596.33	187.80
753	1 575.36	190.30	971	1 597.18	187.70
761	1 576.19	190.20	980	1 598.04	187.60
770	1 577.02	190.10	988	1 598.89	187.50
778	1 577.85	190.00	997	1 599.74	187.40
786	1 578.68	189.90	6006	1 600.60	187.30
795	1 579.51	189.80	6014	1 601.45	187.20
803	1 580.35	189.70	6023	1 602.31	187.10
811	1 581.18	189.60	6031	1 603.16	187.00
820	1 582.01	189.50	6040	1 604.02	186.90
828	1 582.85	189.40	6048	1 604.88	186.80
836	1 583.69	189.30	6057	1 605.74	186.70
845	1 584.52	189.20	6066	1 606.60	186.60
853	1 585.36	189.10	6074	1 607.46	186.50
862	1 586.20	189.00	6083	1 608.32	186.40
870	1 587.04	188.90	6091	1 609.19	186.30
878	1 587.88	188.80	6100	1 610.05	186.20
887	1 588.72	188.70	6109	1 610.92	186.10
895	1 589.56	188.60	6117	1 611.78	186.00
904	1 590.41	188.50			

*1 The value which omitted and computed the 3rd place below the decimal point

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Forward Current of LD	I_F	300	mA
Reverse Voltage of LD	V_R	2.0	V
Forward Current of PD	I_F	10	mA
Reverse Voltage of PD	V_R	20	V
Operating Case Temperature	T_C	-20 to +70	°C
Storage Temperature	T_{stg}	-40 to +85	°C
Lead Soldering Temperature	T_{sld}	260 (10 sec.)	°C

ELECTRO-OPTICAL CHARACTERISTICS ($T_{LD} = T_{set}$, $T_C = -20$ to $+70^\circ\text{C}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Laser Set Temperature	T_{set}		20		35	°C
Forward Voltage	V_F	$P_f = 20$ mW		1.2	1.5	V
Forward Current	I_F	$P_f = 20$ mW		120	167	mA
Threshold Current	I_{th}			20	40	mA
Optical Output Power from Fiber	P_f	$I_F = 167$ mA	20			mW
Peak Emission Wavelength	λ_p	$P_f = 20$ mW, CW, $T_{LD} = T_{set}$	1 527.99	ITU-T ⁻¹	1 611.78	nm
Spectral Line Width	$\Delta\nu$	$P_f = 20$ mW, CW, 3 dB down		1	2	MHz
Side Mode Suppression Ratio	SMSR	$P_f = 20$ mW, CW	33	45		dB
Relative Intensity Noise	RIN	$P_f = 20$ mW, 20 MHz to 3 GHz			-150	dB/Hz
Polarization Extinction Ratio ^{*2}	ext	$P_f = 20$ mW, CW	20			dB

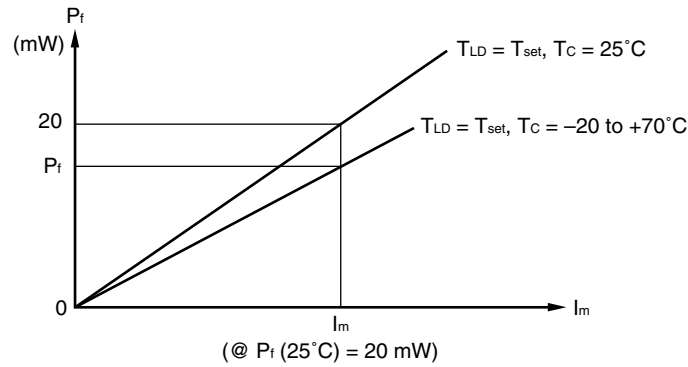
*1 Available for DWDM wavelengths based on ITU-T recommendations (100 GHz grid, please refer to the **ORDERING INFORMATION**)

*2 Polarization state of LD is aligned parallel to the slow axis.

ELECTRO-OPTICAL CHARACTERISTICS
(Applicable to Monitor PD: T_{LD} = T_{set}, T_C = -20 to +70°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Monitor Current	I _m	P _f = 20 mW, V _R = 5 V	100		2 000	μA
Dark Current	I _d	V _R = 5 V			10	nA
Tracking Error	γ ⁻¹	I _m = const.			0.5	dB

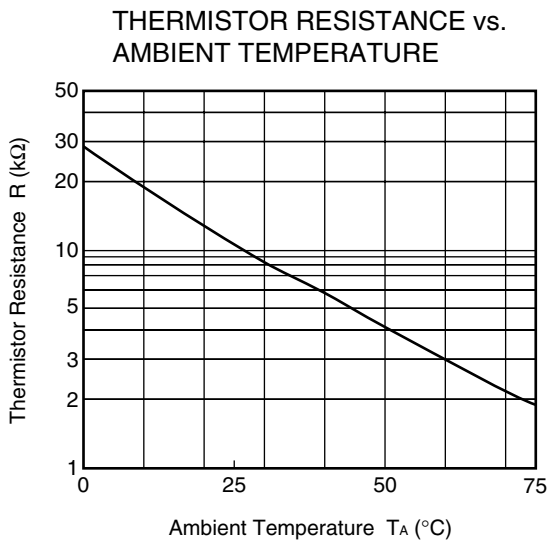
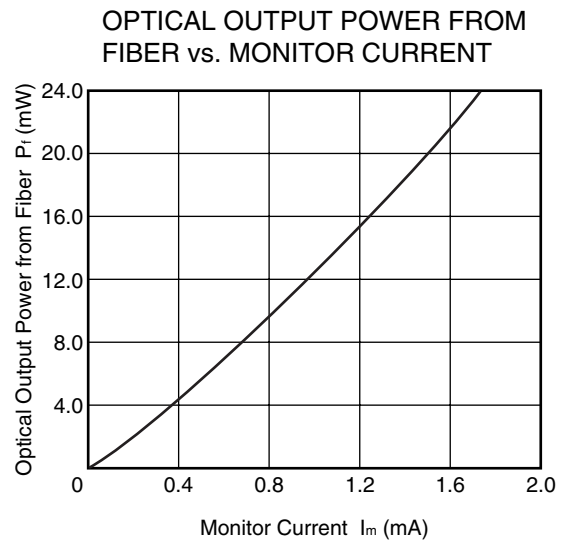
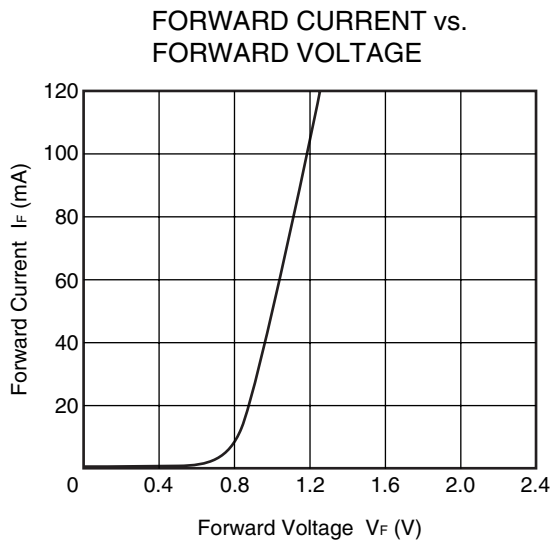
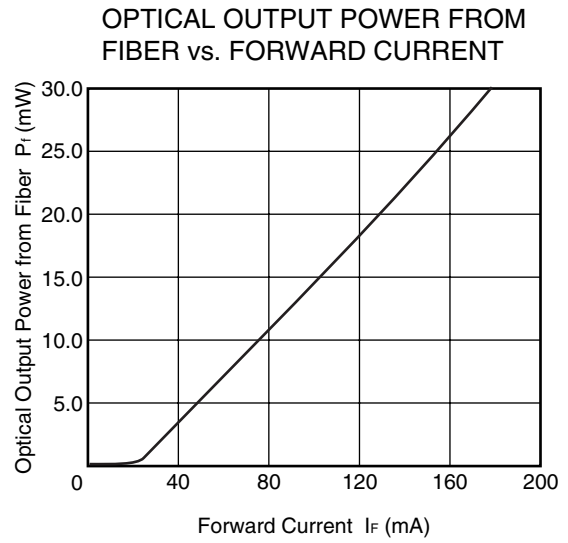
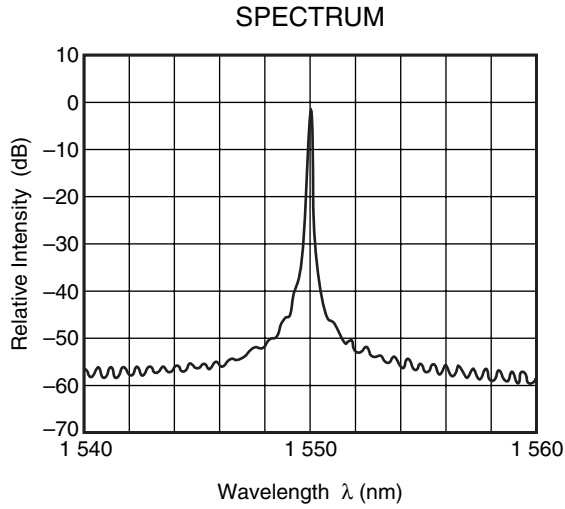
$$*1 \gamma = \left| 10 \log \frac{P_f}{20 \text{ mW}} \right|$$



ELECTRO-OPTICAL CHARACTERISTICS
(Applicable to Thermistor and TEC: T_{LD} = T_{set}, T_C = -20 to +70°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Thermistor Resistance	R	T _{LD} = 25°C	9.5	10.0	10.5	kΩ
B Constant	B		3 350	3 450	3 550	K
Cooler Current	I _c	ΔT = 70 - T _{set} , P _f = 20 mW			1.0	A
Cooler Voltage	V _c	ΔT = 70 - T _{set} , P _f = 20 mW			2.0	V

TYPICAL CHARACTERISTICS ($T_c = T_{set}$, unless otherwise specified)



Remark The graphs indicate nominal characteristics.

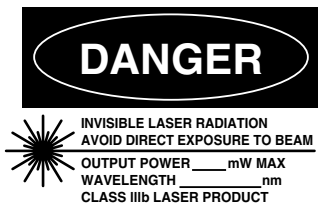
REFERENCE

Document Name	Document No.
OPTICAL SEMICONDUCTOR DEVICES FOR FIBEROPTIC COMMUNICATIONS SELECTION GUIDE	PL10161E
Opto-Electronics Devices Pamphlet	PX10160E

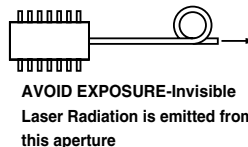
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- M8E 00.4-0110

SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



<p>Warning Laser Beam</p>	<p>A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight.</p> <ul style="list-style-type: none"> • Do not look directly into the laser beam. • Avoid exposure to the laser beam, any reflected or collimated beam.
<p>Caution GaAs Products</p>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. <ol style="list-style-type: none"> 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.
<p>Caution Optical Fiber</p>	<p>A glass-fiber is attached on the product. Handle with care.</p> <ul style="list-style-type: none"> • When the fiber is broken or damaged, handle carefully to avoid injury from the damaged part or fragments.

► For further information, please contact

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